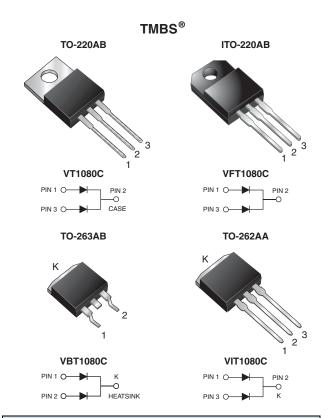


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## **Dual Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.49 \text{ V}$  at  $I_F = 3 \text{ A}$ 



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 5 A					
V <sub>RRM</sub>	80 V					
I <sub>FSM</sub>	80 A					
V <sub>F</sub> at I <sub>F</sub> = 5 A	0.57 V					
T <sub>J</sub> max.	150 °C					
Package	TO-220AB, ITO-220AB, TO-263AB, TO-262AA					
Circuit configuration	Common cathode					

#### **FEATURES**





· Low forward voltage drop, low power losses

• High efficiency operation

RoHS

 Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)

 Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)

 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **TYPICAL APPLICATIONS**

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

#### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	VT1080C	VFT1080C	VBT1080C	VIT1080C	UNIT		
Maximum repetitive peak reverse voltage		$V_{RRM}$	V <sub>RRM</sub> 80				V	
Maximum average forward rectified current (fig. 1)	per device	I=	10			А		
	per diode	I <sub>F(AV)</sub>						
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	-sm 80				Α	
Non-repetitive avalanche energy at $T_J = 25~^{\circ}\text{C}$ , $L = 60~\text{mH}$ per diode		E <sub>AS</sub>	30				mJ	
Peak repetitive reverse current at $t_p$ = 2 $\mu$ s, 1 kHz, $T_J$ = 38 °C ± 2 °C per diode		I <sub>RRM</sub>	1.0			Α		
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000				V/µs	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V <sub>AC</sub>	1500				V	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150				°C	

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Breakdown voltage	$I_R = 10 \text{ mA}$	T <sub>A</sub> = 25 °C	$V_{BR}$	80 (minimum)	=	V		
Instantaneous forward voltage per diode	I <sub>F</sub> = 3 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.54	=	V		
	I <sub>F</sub> = 5 A			0.63	0.72			
	I <sub>F</sub> = 3 A	T <sub>A</sub> = 125 °C		0.49	=			
	I <sub>F</sub> = 5 A			0.57	0.66			
Reverse current per diode	V - 80 V	T <sub>A</sub> = 25 °C	1 (2)	12	400	μA		
	$V_{R} = 80 \text{ V}$ $T_{A} = 125 \text{ °C}$	I <sub>R</sub> <sup>(2)</sup>	6	15	mA			

#### Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq$  40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	VT1080C					
Typical thormal registance	per diode	$R_{ hetaJC}$	3.5	6.5	3.5	3.5	°C/W
Typical thermal resistance	per device		2.5	5.5	2.5	2.5	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	VT1080C-E3/4W	1.88	4W	50/tube	Tube			
ITO-220AB	VFT1080C-E3/4W	1.70	4W	50/tube	Tube			
TO-263AB	VBT1080C-E3/4W	1.35	4W	50/tube	Tube			
TO-263AB	VBT1080C-E3/8W	1.35	8W	800/reel	Tape and reel			
TO-262AA	VIT1080C-E3/4W	1.43	4W	50/tube	Tube			

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### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

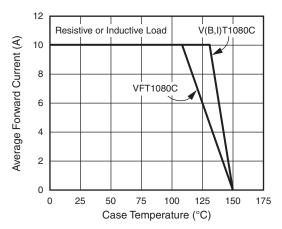


Fig. 1 - Maximum Forward Current Derating Curve

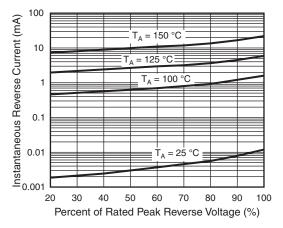


Fig. 4 - Typical Reverse Characteristics Per Diode

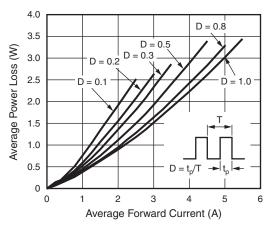


Fig. 2 - Forward Power Loss Characteristics Per Diode

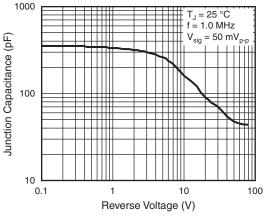


Fig. 5 - Typical Junction Capacitance Per Diode

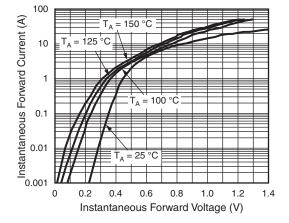


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

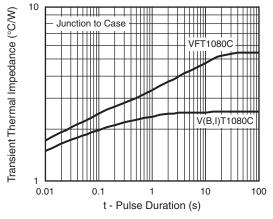
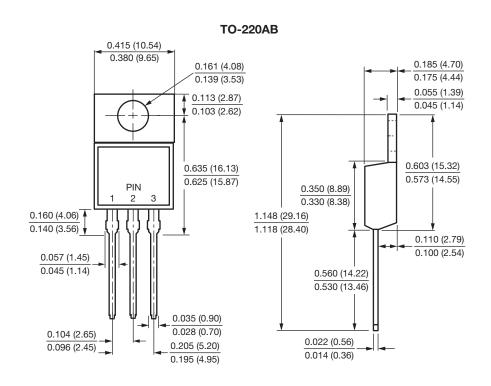


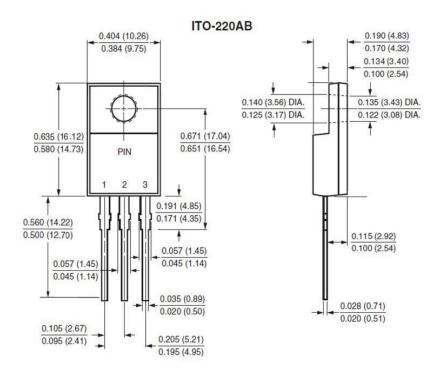
Fig. 6 - Typical Transient Thermal Impedance Per Diode

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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

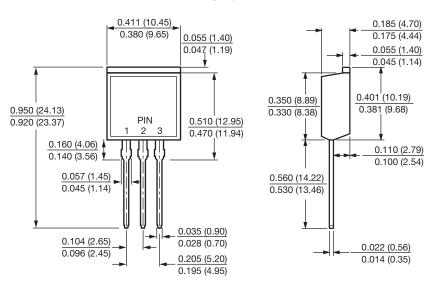




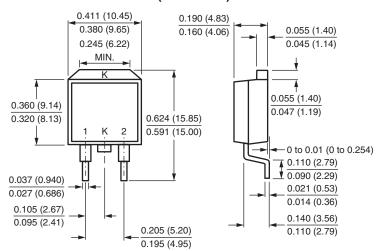
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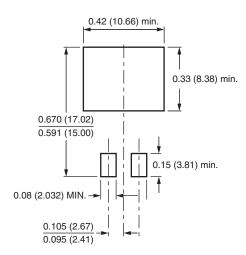
#### TO-262AA



### D<sup>2</sup>PAK (TO-263AB)



#### **Mounting Pad Layout**



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